

# **PUMB3H**

50 V, 100 mA PNP/PNP Resistor-Equipped double Transistor; R1 = 4.7 k $\Omega$ , R2 = open

22 March 2021

Product data sheet

## 1. General description

PNP/PNP Resistor-Equipped double Transistor (RET) in a very small SOT363 (SC-88) Surface-Mounted Device (SMD) plastic package.

NPN/NPN complement: PUMH7H NPN/PNP complement: PUMD6H

#### 2. Features and benefits

- 100 mA output current capability
- Built-in resistors
- · Simplifies circuit design
- · Reduces component count
- · Reduces pick and place costs
- High-temperature applications up to 175 °C

### 3. Applications

- Digital applications
- Cost saving alternative for BC857 series in digital applications
- · Controlling IC inputs
- Switching loads

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor							
V <sub>CEO</sub>	collector-emitter voltage	open base		-	-	-50	V
Io	output current			-	-	-100	mA
R1	bias resistor 1	T <sub>amb</sub> = 25 °C	[1]	3.3	4.7	6.1	kΩ

[1] See section "Test information" for resistor calculation and test conditions



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## 5. Pinning information

**Table 2. Pinning information** 

Pin	Symbol	Description	Simplified outline	Graphic symbol	
1	GND1	GND (emitter) TR1	□6 □5 □4	O1 I2 GND2	
2	l1	input (base) TR1			
3	O2	output (collector) TR2		R1 R	
4	GND2	GND (emitter) TR2	1 1 3 TSSOP6 (SOT363)	H <sub>1</sub> H <sub>2</sub> H <sub>3</sub>	TR1
5	12	input (base) TR2		R1	
6	01	output (collector) TR1			
				GND1 I1 O2 006aaa268	

## 6. Ordering information

**Table 3. Ordering information** 

Type number	Package		
	Name	Description	Version
PUMB3H		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	SOT363

# 7. Marking

#### Table 4. Marking codes

Type number	Marking code[1]
PUMB3H	2C%

[1] % = placeholder for manufacturing site code

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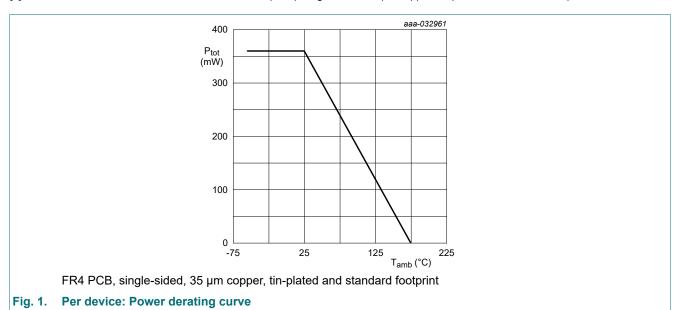
## 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transiste	or					_
V <sub>CBO</sub>	collector-base voltage	open emitter		-	-50	V
$V_{CEO}$	collector-emitter voltage	open base		-	-50	V
$V_{EBO}$	emitter-base voltage	open collector		-	-7	V
V <sub>I</sub>	input voltage			-30	7	V
Io	output current			-	-100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	240	mW
Per device						
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	360	mW
Tj	junction temperature			-	175	°C
T <sub>amb</sub>	ambient temperature			-55	175	°C
T <sub>stg</sub>	storage temperature			-65	175	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.



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### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	tor						'
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	-	230	K/W
Per device	'				-	1	
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	417	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided, 35 µm copper, tin-plated and standard footprint.

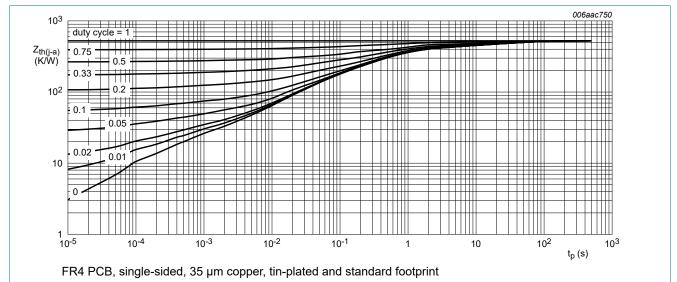


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

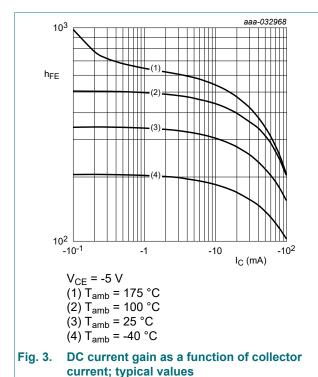
50 V, 100 mA PNP/PNP Resistor-Equipped double Transistor; R1 = 4.7 k $\Omega$ , R2 = open

### 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	tor						
V <sub>(BR)CBO</sub>	collector-base breakdown voltage	$I_C = -100 \mu A; I_E = 0 A; T_{amb} = 25 °C$		-50	-	-	V
$V_{(BR)CEO}$	collector-emitter breakdown voltage	I <sub>C</sub> = -2 mA; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C		-50	-	-	V
I <sub>CBO</sub>	collector-base cut-off current	CB of the allip and		-	-	-100	nA
I <sub>CEO</sub>	collector-emitter cut-off	V <sub>CE</sub> = -30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	-100	nA
	current	V <sub>CE</sub> = -30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 150 °C		-	-	-5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = -7 V; I <sub>C</sub> = 0 mA; T <sub>amb</sub> = 25 °C		-	-	-100	nA
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -1 mA; T <sub>amb</sub> = 25 °C		200	-	-	
V <sub>CEsat</sub>	collector-emitter $I_C$ = -10 mA; $I_B$ = -0.5 mA; $T_{amb}$ = 25 °C saturation voltage			-	-	-100	mV
V <sub>I(off)</sub>	off-state input voltage	V <sub>CE</sub> = -5 V; I <sub>C</sub> = -100 μA; T <sub>amb</sub> = 25 °C		-	-585	-500	mV
V <sub>I(on)</sub>	on-state input voltage	$V_{CE}$ = -0.3 V; $I_{C}$ = -10 mA; $T_{amb}$ = 25 °C		-1.3	-0.88	-	V
R1	bias resistor 1	T <sub>amb</sub> = 25 °C	[1]	3.3	4.7	6.1	kΩ
C <sub>c</sub>	collector capacitance	<sub>CB</sub> = -10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; = 1 MHz; T <sub>amb</sub> = 25 °C		-	-	3	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = -5 V; $I_{C}$ = -10 mA; f = 100 MHz; $T_{amb}$ = 25 °C	[2]	-	180	-	MHz

- [1] See section "Test information" for resistor calculation and test conditions
- [2] Characteristics of built-in transistor



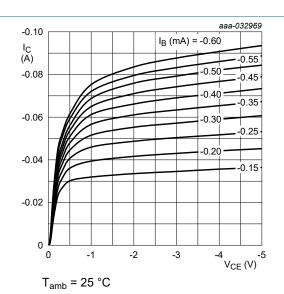
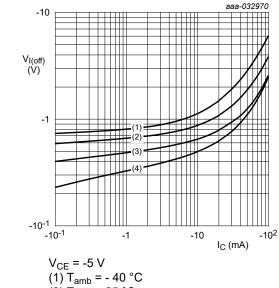


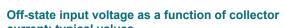
Fig. 4. Collector current as a function of collectoremitter voltage; typical values

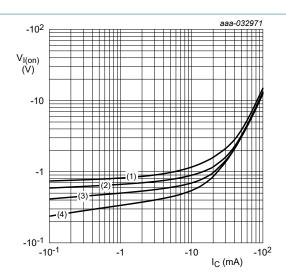
#### 50 V, 100 mA PNP/PNP Resistor-Equipped double Transistor; R1 = 4.7 k $\Omega$ , R2 = open



 $(2) T_{amb} = 25 °C$ 

(3) T<sub>amb</sub> = 100 °C (4) T<sub>amb</sub> = 175 °C

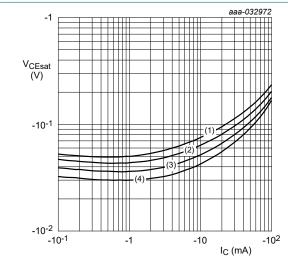




V<sub>CE</sub> = -0.3 V (1) T<sub>amb</sub> = - 40 °C (2) T<sub>amb</sub> = 25 °C

(3) T<sub>amb</sub> = 100 °C (4) T<sub>amb</sub> = 175 °C

Off-state input voltage as a function of collector | Fig. 6. On-state input voltage as a function of collector Fig. 5. current; typical values current; typical values



 $I_{\rm C}/I_{\rm B}=20$ 

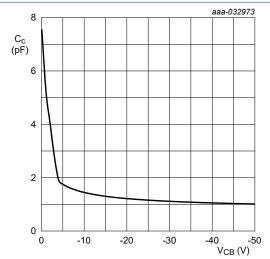
 $(1) T_{amb} = 175 °C$ 

(2)  $T_{amb} = 100 \, ^{\circ}C$ 

(3)  $T_{amb} = 25 \, ^{\circ}C$ 

(4)  $T_{amb} = -40 \, ^{\circ}C$ 

Collector-emitter saturation voltage as a Fig. 7. function of collector current; typical values

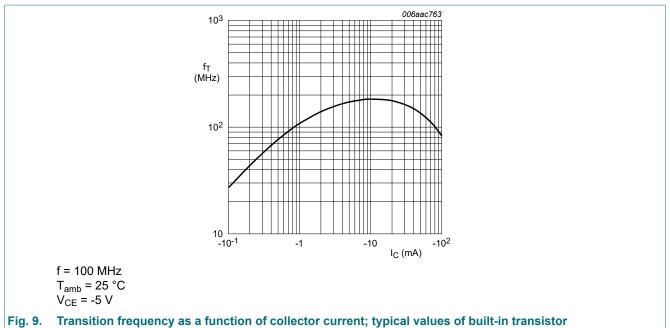


f = 1 MHz $T_{amb} = 25 \, ^{\circ}C$ 

Collector capacitance as a function of collector-Fig. 8. base voltage; typical values

6/12

### 50 V, 100 mA PNP/PNP Resistor-Equipped double Transistor; R1 = 4.7 k $\Omega$ , R2 = open

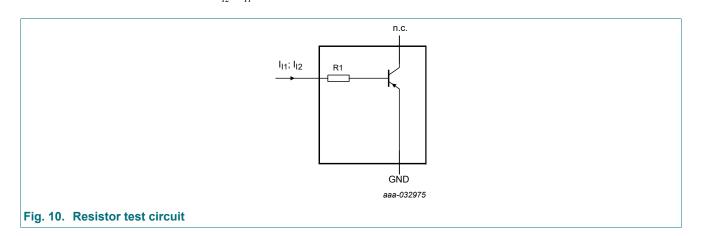


50 V, 100 mA PNP/PNP Resistor-Equipped double Transistor; R1 = 4.7 k $\Omega$ , R2 = open

## 11. Test information

#### **Resistor calculation**

• Calculation of bias resistor 1 (R1)  $R_I = \frac{V(I_{I2}) - V(I_{II})}{I_{I2} - I_{II}}$ 

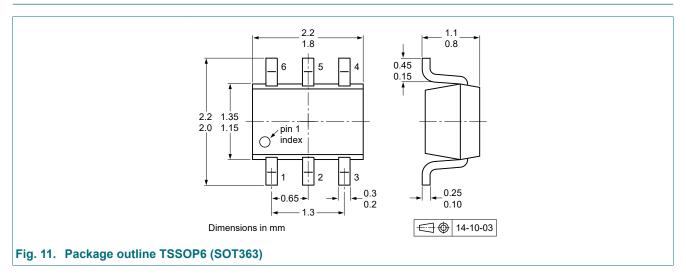


### Resistor test conditions

#### **Table 8. Resistor test conditions**

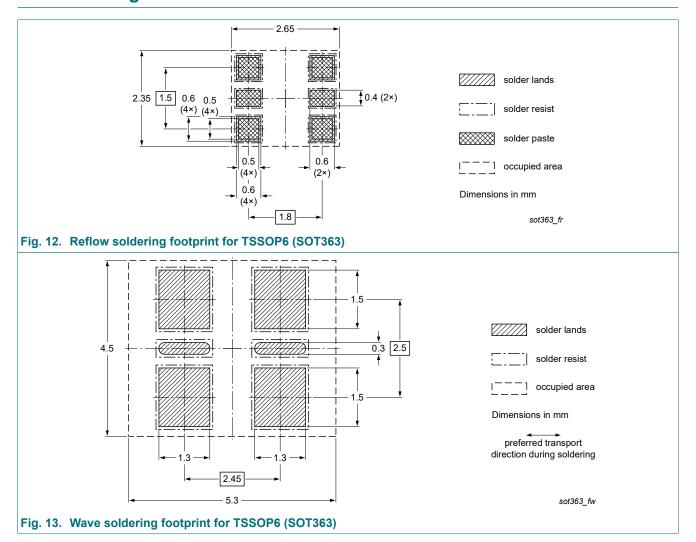
Type number	R1 (kΩ)	R2 (kΩ)	Test conditions						
			I <sub>11</sub>	I <sub>I2</sub>					
Per transistor									
PUMB3H	4.7	open	-600 µA	-700 μA					

## 12. Package outline



50 V, 100 mA PNP/PNP Resistor-Equipped double Transistor; R1 = 4.7 k $\Omega$ , R2 = open

## 13. Soldering



50 V, 100 mA PNP/PNP Resistor-Equipped double Transistor; R1 = 4.7 k $\Omega$ , R2 = open

## 14. Revision history

### Table 9. Revision history

Data sheet ID	Release date		Change notice	Supersedes
PUMB3H v.1	20210322	Product data sheet	-	-

#### 50 V, 100 mA PNP/PNP Resistor-Equipped double Transistor; R1 = 4.7 k $\Omega$ , R2 = open

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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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## **Contents**

1. General description	
2. Features and benefits	
3. Applications	
4. Quick reference data	
5. Pinning information	2
6. Ordering information	2
7. Marking	
8. Limiting values	3
9. Thermal characteristics	4
10. Characteristics	5
11. Test information	8
12. Package outline	8
13. Soldering	
14. Revision history	10
15. Legal information	

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